Unit: mm

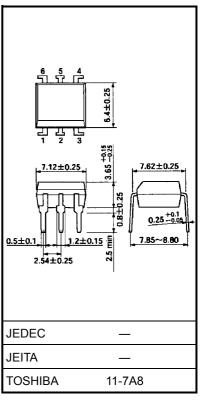
TOSHIBA Photocoupler GaAlAs IRED + Photo IC

TLP512

Digital Logic Ground Isolation
Line Receiver
Microprocessor System Interfaces
Switching Power Supply Feedback Control
Transistor Inverter

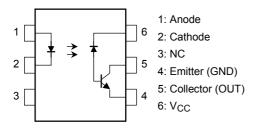
The TLP512 consists of a GaAlAs high-output light emitting diode and a high-speed detector that contains a PN photodiode and an amplifier transistor into a single chip.

- Isolation voltage: 2500 Vrms (min)
- Switching speed: t_{pHL} = 0.8 μs , t_{pLH} = 0.8 μs (max) @RL = 1.9 $k\Omega$
- TTL compatible
- UL recognized: UL1577, file No. E67349

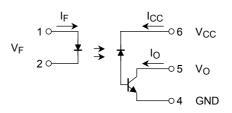


Weight: 0.4 g (typ.)

Pin Configuration (top view)



Schematic



Maximum Ratings (Ta = 25°C)

Characteristics			Symbol	Rating	Unit
	DC forward current	(Note 1)	l _F	25	mA
	Pulse forward current	(Note 2)	I _{FP}	50	mA
LED	Peak transient forward current	(Note 3)	I _{FPT}	1	Α
	DC reverse voltage		V _R	5	V
	Diode power dissipation	(Note 4)	P _D	45	mW
	Output current		IO	8	mA
Detector	Peak output current		I _{OP}	16	mA
	Output voltage		Vo	-0.5 to 15	V
ă	Supply voltage		V _{CC}	-0.5 to 15	V
	Output power dissipation	(Note 5)	Po	100	mW
Ope	Operating temperature range		T _{opr}	-55 to 100	°C
Storage temperature range			T _{stg}	-55 to 125	°C
Sold	Soldering temperature (10 s) (Note 6)			260	°C
Isola	Isolation voltage (R.H. ≤ 60%, AC 1 min) (Note 7)			2500	Vrms

- Note 1: Decreases at the rate of 0.8 mA/°C with the ambient temperature of 70°C or higher.
- Note 2: Duty cycle of 50%, pulse width of 1 ms.

 Decreases at the rate of 1.6 mA/°C with the ambient temperature of 70°C or higher.
- Note 3: Pulse width \leq 1 μ s, 300 pps
- Note 4: Decreases at the rate of 0.9 mW/°C with the ambient temperature of 70°C or higher.
- Note 5: Decreases at the rate of 2 mW/°C with the ambient temperature of 70°C or higher.
- Note 6: Soldering is performed 2 mm from the bottom of the package.
- Note 7: Device considered a two-terminal device: pins 1, 2, and 3 shorted together and pins 4, 5 and 6 shorted together.

Electrical Characteristics (Ta = 25°C)

Characteristic		Symbol	Test Condition	Min	Тур.	Max	Unit
	Forward voltage	V _F	I _F = 16 mA	_	1.65	1.85	V
LED	Forward voltage temperature coefficient	ΔV _F /ΔTa	I _F = 16 mA	_	-2	_	mV/°C
	Reverse current	I _R	V _R = 5 V	_	_	10	μА
	Pin-to-pin capacitance	C _T	V _F = 0, f = 1 MHz	_	4.5	_	pF
Detector		I _{OH} (1)	$I_F = 0 \text{ mA}, V_{CC} = V_O = 5.5 \text{ V}$	_	3	500	nA
	High-level output current	I _{OH} (2)	$I_F = 0 \text{ mA}, V_{CC} = V_O = 15 \text{ V}$	_	_	5	
		I _{OH}	$I_F = 0 \text{ mA}, V_{CC} = V_O = 15 \text{ V}$ Ta = 70°C	_	_	50	μА
	High-level supply current	Іссн	I _F = 0 mA, V _{CC} = 15 V	—	0.01	1	μΑ

Coupled Electrical Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Current transfer ratio	lo/le	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $V_O = 0.4 \text{ V}$	20	40	_	%
Current transfer fatto	I _O /I _F	I _F = 16 mA, V _{CC} = 4.5 V V _O = 0.4 V, Ta = 0 to 70°C	15	_	_	70
Low-level output voltage	V _{OL}	$I_F = 16 \text{ mA}, V_{CC} = 4.5 \text{ V}$ $I_O = 2.4 \text{ mA}$			0.4	V

Isolation Characteristics (Ta = 25°C)

Characteristic	Symbol	Test Condition	Min	Тур.	Max	Unit
Capacitance input to output	CS	$V_S = 0$, $f = 1$ MHz (Note 7)	_	0.8	_	pF
Isolation resistance	R _S	R.H. \leq 60%, V _S = 500 V (Note 7)	5 × 10 ¹⁰	10 ¹⁴	_	Ω
		AC 1 min	2500	_	_	Vrms
Isolation voltage	BV_S	AC 1 s, in oil	_	5000	_	VIIIIS
		DC 1 min, in oil	_	5000	_	V_{dc}

Switching Characteristics (Ta = 25°C)

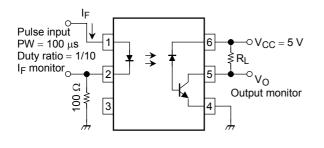
Characteristics	Symbol	Test Circuit	Test Condition	Min	Тур.	Max	Unit
Propagation delay time (H \rightarrow L)	t _{pHL}	1	$I_F = 0 \rightarrow 16 \text{ mA}, R_L = 1.9 \text{ k}\Omega$	_	_	0.8	μS
Propagation delay time (L \rightarrow H)	t _{pLH}] '	$I_F = 16 \rightarrow 0 \text{ mA}, R_L = 1.9 \text{ k}\Omega$	_	_	0.8	μS
Common mode transient immunity at logic high output (Note 8)	CM _H	2	I_F = 0 mA, V_{CM} = 200 V_{P-P} R_L = 1.9 $k\Omega$	_	1500	_	V/μs
Common mode transient immunity at logic low output (Note 8)	CML		$I_F = 16 \text{ mA}, V_{CM} = 200 \text{ Vp-p}$ $R_L = 1.9 \text{ k}\Omega$		-1500		V/μs

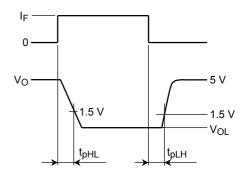
Note 8: Common mode transient immunity in logic high level is the maximum tolerable (positive) dV_{CM}/dt on the leading edge of the common mode pulse, V_{CM} , to assure that the output will remain in a logic high state $(V_{OUT} > 2.0 \text{ V})$.

Common mode transient immunity in logic low level is the maximum tolerable (negative) dV_{CM}/dt on the trailing edge of the common mode pulse, V_{CM} , to assure that the output will remain in a logic low state $(V_{OUT} < 0.8 \text{ V})$.

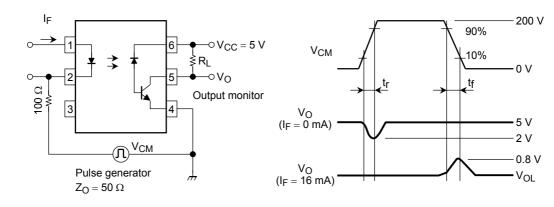
Note 9: Electrostatic discharge immunity (pin to pin): 100 V (max) ($C \le 200$ pF, R = 0)

Test Circuit 1: Switching Time Test Circuit

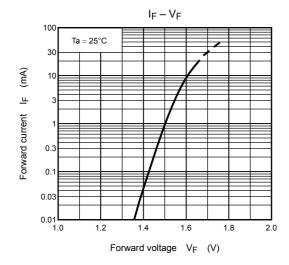


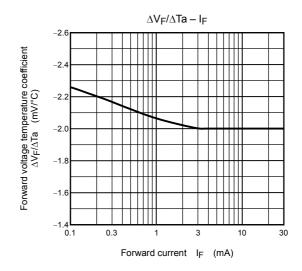


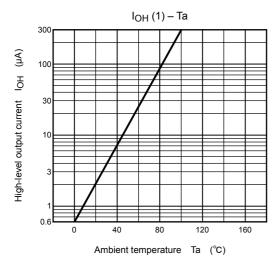
Test Circuit 2: Common Mode Noise Immunity Test Circuit

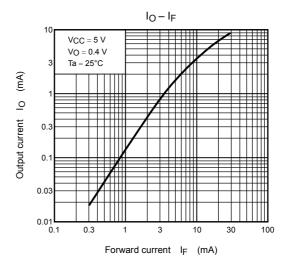


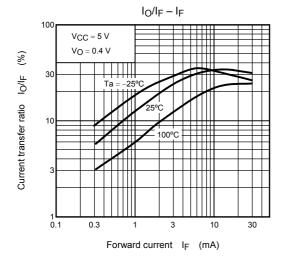
$$CM_{H} = \frac{160 (V)}{t_{r} (\mu s)}, CM_{L} = \frac{160 (V)}{t_{f} (\mu s)}$$

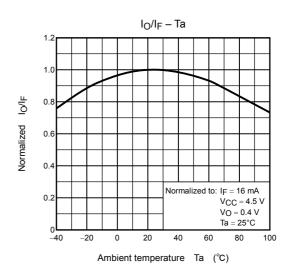




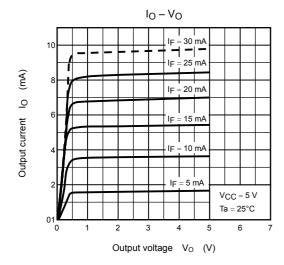


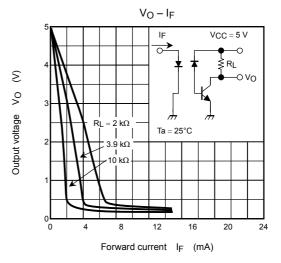


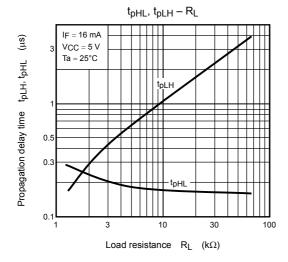




^{*:} The above graphs show typical characteristics.







^{*:} The above graphs show typical characteristics.

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